# Agilent HSDL-3003 IrDA® Data Compliant Low Power 115.2 kbit/s with Remote Control Infrared Transceiver

**Data Sheet** 



#### Description

The HSDL-3003 is a small form factor enhanced infrared (IR) transceiver module that provides the capability of (1) interface between logic and IR signals for through-air, serial, half-duplex IR data link, and (2) IR remote control transmission operating at the optimum 940 nm wavelength for universal remote control applications.

For IR data communication, the HSDL-3003 provides the flexibility of low power SIR applications and remote control applications with no external components needed for the selection of the type of application. The transceiver is compliant to IrDA® Physical

#### IrDA<sup>®</sup> Data Features

- Fully compliant to IrDA® Physical Layer Specification 1.4 low power from 9.6 kbit/s to 115.2 kbit/s (SIR)
  - Excellent nose-to-nose operation
  - Link distance up to 50 cm typically
- Complete shutdown for TxD\_IrDA, RxD\_IrDA, and PIN diode
- Low power consumption
  - Low idle current, 50 μA typically
  - Low shutdown current, 10 nA typically
- LED stuck-high protection

#### Applications

- Mobile data communication and universal remote control transmission
  - Personal digital assistants (PDAs)
  - Mobile phones

**General Features** 

- Guaranteed temperature performance, –20° to 70°C
  - Critical parameters are guaranteed over temperature and supply voltage
- Low power consumption
- Small module size
- Height: 2.70 mm
- Width: 8.00 mm
- Depth: 2.95 mm
- Minimum external components
  - Integrated single-biased LED resistor
  - Direct interoperability to MPU
  - Programmable Txd features
  - Integrated remote control FET
- Withstands >100 mV<sub>p-p</sub> power supply ripple typically
- V<sub>CC</sub> supply 2.4 to 3.6 volts
- Integrated EMI shield
- Designed to accommodate light loss with cosmetic windows
- IEC 825-Class 1 eye safe

#### **Remote Control Features**

- Wide angle and high radiant intensity
- Spectrally suited to remote control transmission function at 940 nm typically
- Typical link distance up to 8 meters

**CAUTION:** The BiCMOS inherent to this design of this component increases the component's susceptibility to damage from Electrostatic Discharge (ESD). It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation, which may be induced by ESD.



Layer Specification Version 1.4 Low Power from 9.6 kbit/s to 115.2 kbit/s (SIR) and it is IEC 825-Class 1 Eye Safe.

The HSDL-3003 has very low idle current and can be shutdown completely to achieve very low power consumption. In the shutdown mode, the PIN diode will be inactive and thus producing very little photocurrent even under very bright ambient light. Such features are ideal for battery operated handheld products such as PDAs and mobile phones.

#### **Order Information**

Part Number	Packaging Type	Package	Quantity
HSDL-3003-021	Tape and Reel	Front View	2500

#### **Marking Information**

The unit is marked with 'yyww' on the shield yy = year ww = work week

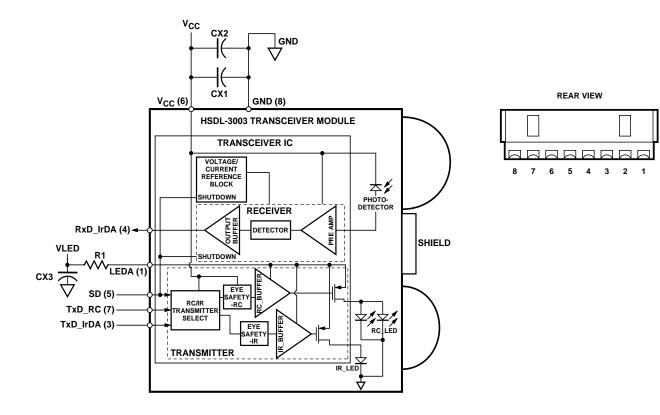


Figure 1. Functional block diagram of low power IrDA link distance and remote control.

### I/O Pins Configuration Table

Pin	Symbol	I/0	Description	Notes
1	LEDA	I	IR and Remote Control LED Driver	Tied through external resistor, R1, to VLED from 2.4 to 4.5 Volt
2	N.C.	_	No Connection	No Connection
3	TxD_IrDA	I	IrDA Transmitter Data Input. Active High	Logic high turns on the IrDA LED. If held HIGH longer than ~50 µs, the IrDA LED is turned off. TxD_IrDA must be driven either HIGH or LOW. Do not leave the pin floating
4	RxD_IrDA	0	IrDA Receiver Data Output. Active Low	Output is at LOW pulse response when light pulse is seen
5	SD	I	Shutdown. Active High	Complete shutdown TxD_IrDA, RxD_IrDA, and PIN diode. Do not leave the pin floating
6	Vcc	I	Supply Voltage	Regulated, 2.4 to 3.6 Volt
7	TxD_RC	I	Remote Control Transmission Input. Active High	Logic high turns on the RC LED. If held HIGH longer than ~50 µs, the RC LED is turned off. TxD_RC must be driven either HIGH or LOW. Do not leave the pin floating
8	GND	I	Connect to System Ground	Tie this pin to system ground
_	Shield	-	EMI Shield	Tie to system ground via a low inductance trace. For best performance, do not tie it to the HSDL-3003 GND pin directly

#### **Recommended Application Circuit Components**

Recommended Value				
1.8 $\Omega\pm$ 5%, 0.25 Watt for 2.4 $\leq$ VLED $\leq$ 2.7 V				
2.7 $\Omega\pm$ 5%, 0.25 Watt for 2.7 $\leq$ VLED $\leq$ 3.3 V				
$\overline{\textbf{3.3}\ \Omega\pm\textbf{5\%},\textbf{0.25}}$ Watt for $\textbf{3.0}\leq\textbf{VLED}\leq\textbf{3.6}$ V				
4.7 $\Omega \pm 5\%$ , 0.25 Watt for 3.6 $\leq$ VLED $\leq$ 4.5 V				
0.47 $\mu F\pm$ 20%, X7R Ceramic				
6.8 $\mu\text{F}\pm20\%$ , Tantalum				
6.8 $\mu\text{F}\pm$ 20%, Tantalum				

Notes:

1. CX1 must be placed within 0.7 cm of HSDL-3003 to obtain optimum noise immunity.

2. The supply rejection performance can be enhanced by including CX2, as shown in Figure 1, in environment with noisy power supplies.

#### Different Remote Control Configurations for HSDL-3003

The HSDL-3003 can operate in the single-TXD programmable mode or the two-TXD direct transmission mode.

#### Single-TXD Programmable Mode

In the single-TXD programmable mode, only one input pin (TxD\_IrDA input pin) is used to turn on either the 875 nm LED or the 940 nm LEDs while the TxD\_RC input pin is grounded.

The transceiver is in default mode (IrDA) when powered up. User needs to apply the following programming sequence to both the TxD\_IrDA and SD inputs to enable the transceiver to operate in either the IrDA or remote control mode.

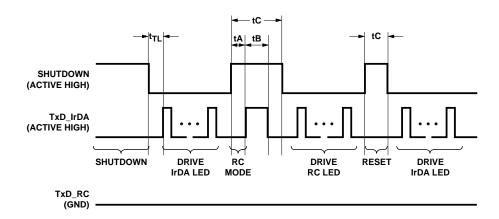


Figure 2.

#### **Two-TXD Direct Transmission Mode**

In the two-TXD direct transmission mode, the 875 nm LED and the 940 nm LEDs are turned on separately by two different input pins. The TxD\_IrDA input pin is used to turn on the 875 nm LED while the TxD\_RC input pin is used to turn on the 940 nm LEDs.

Please refer to the Transceiver I/O truth table for more details.

#### Transceiver Control I/O Truth Table for Two-TXD Direct Transmission Mode

SD	TXD_IrDA	TXD_RC	IrDA LED	RC LEDs	Remarks	
0	0	0	OFF	OFF	IR Rx enabled. Idle mode	
0	0	1	OFF	ON	Remote control operation	
0	1	0	ON	OFF	IrDA Tx operation	
0	1	1	DIM	ON	Not recommended	
1	0	0	OFF	OFF	Shutdown mode*	

\* The shutdown condition will set the transceiver to the default mode (IrDA).

Absolute Maximum Ratings at  $T_A$  = 25°C For implementations where case to ambient thermal resistance is  $\leq$  50°C/W

Parameter	Symbol	Min.	Max.	Units	Conditions
Storage Temperature	Ts	-40	100	°C	
Operating Temperature	TA	-20	70	°C	
LED Supply Voltage	V <sub>LED</sub>	0	6	V	
Supply Voltage	Vcc	0	6	V	
Output Voltage: RxD	Vo	0	6	V	
Total LED Current Pulse Amplitude	I <sub>VLED</sub>		580	mA	≤ 90 µs Pulse Width ≤ 20% Duty Cycle
IR LED Current Pulse Amplitude	(Ivled)ir		280	mA	≤ 90 µs Pulse Width ≤ 20% Duty Cycle
RC LED Current Pulse Amplitude	(I <sub>VLED</sub> )rc		580	mA	≤ 90 µs Pulse Width ≤ 20% Duty Cycle

## **Recommended Operating Conditions**

Parameter		Symbol	Min.	Max.	Units	Conditions
Operating Temperature		TA	-20	70	°C	
Supply Voltage		Vcc	2.4	3.6	V	
LED Supply Voltage		VLED	2.4	4.5	V	
Logic Input Voltage	Logic High	Vih	2/3 Vcc	Vcc	V	
for TxD_IrDA, TxD_RC	Logic Low	VIL	0	1/3 Vcc	V	
Receiver Input	Logic High	Еін	0.0081	500	mW/cm <sup>2</sup>	For in-band signals $\leq$ 115.2 kbit/s <sup>[3]</sup>
Irradiance	Logic Low	EIL		0.3	$\mu W/cm^2$	For in-band signals <sup>[3]</sup>
TxD_IrDA Pulse Width (SIR)		t <sub>TPW</sub> (SIR)	1.5	1.6	μs	
Receiver Data Rate			9.6	115.2	kbit/s	

**Electrical and Optical Specifications** Specifications (Min. and Max. values) hold over the recommended operating conditions unless otherwise noted. Unspecified test conditions may be anywhere in their operating range. All typical values (Typ.) are at 25 °C with V<sub>CC</sub> at 3.0 V unless otherwise noted.

Parameter		Symbol	Min.	Typ.	Max.	Units	Conditions
Infrared (IrDA) R	Infrared (IrDA) Receiver						
Viewing Angle			30			0	
Peak Sensitivity	Wavelength	λρ		875		nm	
RxD_IrDA	Logic High	Vон	Vcc - 0.2		Vcc	V	I <sub>OH</sub> = -200 $\mu$ A, EI $\leq$ 0.3 $\mu$ W/cm <sup>2</sup>
Output Voltage	Logic Low	Vol	0		0.4	V	
RxD_IrDA Pulse	Width (SIR) <sup>[4]</sup>	t <sub>RPW</sub>	1	2.3	7.5	μs	$\theta_{1/2} \leq 15^{\circ}$ , CL= 9 pF
RxD_IrDA Rise 8	k Fall Times	tr, tf		30	100	ns	CL= 9 pF
Receiver Latenc	y Time <sup>[5]</sup>	tL		26	50	μs	$EI = 9.0 \ \mu W/cm^2$
Receiver Wake l	Jp Time <sup>[6]</sup>	t <sub>RW</sub>		75	200	μs	$EI = 10 \text{ mW/cm}^2$
Infrared (IrDA) T	ransmitter						
IR Radiant Intens	sity	I <sub>EH</sub>	4	13		mW/sr	$\label{eq:lvleda} \begin{split} I_{VLEDA} &= 100 \text{ mA},  \theta_{1/2} \leq 15^\circ, \\ TxD\_IrDA \geq V_{IH},  T_A &= 25^\circ C \end{split}$
IR Viewing Angle	Э	20 <sub>1/2</sub>	30		60	0	
IR Peak Waveler	ngth	λρ		875		nm	
TxD_IrDA	High	VIH	2/3 V <sub>CC</sub>		V <sub>CC</sub>	V	
Logic Levels	Low	V <sub>IL</sub>	0		1/3 V <sub>CC</sub>	V	
TxD_IrDA	High	I <sub>H</sub>		0.02	1	μA	$V_I \ge V_{IH}$
Input Current	Low	۱L		-0.02	1	μA	$0 \le V_I \le V_{IL}$
LED Current	Shutdown	I <sub>VLED</sub>		0.02	10	μA	$V_{I}(SD) \ge V_{IH}$
Wake Up Time <sup>[7]</sup>		t <sub>TW</sub>		180	500	ns	
Data setup time		tA	25			ns	
Data pulsewidth		tB	25			ns	
Programming tin	ne	tC	75			ns	
Maximum Optica Pulse Width <sup>[8]</sup>	al	tpw(Max)			120	μs	
TxD Rise & Fall T (Optical)	Times	tr, tf			600	ns	
LED Anode On-S	tate Voltage	V <sub>ON (LED</sub>	A)	2.4		V	$I_{VLEDA} = 100 \text{ mA}, V_I (TxD) \ge V_{IH}$
Remote Control	(RC) Transmitt	er					
RC Radiant Intensity		I <sub>EH</sub>	15 <sup>[9]</sup>	36		mW/sr	$\label{eq:lvleda} \begin{split} I_{VLEDA} &= 400 \text{ mA},  \theta_{1/2} \leq 15^\circ, \\ TxD\_RC \geq V_{IH},  T_A &= 25^\circ\text{C} \end{split}$
RC Viewing Angle		<b>2</b> θ <sub>1/2</sub>	30		60	0	
RC Peak Wavelength		λ <sub>P</sub>		940		nm	
TxD_RC Logic	High	VIH	2/3 V <sub>CC</sub>		V <sub>CC</sub>	V	
Levels	Low	V <sub>IL</sub>	0		1/3 V <sub>CC</sub>	V	
TxD_RC Input	High	Ι <sub>Η</sub>		0.02	1	μA	$V_I \ge V_{IH}$
Current	Low	١L		-0.02	1	μA	$0 \le V_I \le V_{IL}$
Maximum Optica Width <sup>[8]</sup>	al Pulse	tpw(Max)			120	μs	
LEDA Voltage		V <sub>ON (LED</sub>	A)	1.65	2.3	V	$I_{LEDA}$ = 400 mA, $V_I(TxD) \ge V_{IH}$

#### Transceiver

Parameters		Symbol	Min.	Тур.	Max.	Units	Conditions
Input Current	High	lΗ		0.01	1	μΑ	$V_I \geq V_{IH}$
	Low	١L	-1	-0.02	1	μA	$0 \le V_I \le V_{IL}$
Supply Current	Shutdown	Icc1		0.01	1	μA	$V_{SD} \ge V_{CC}$ - 0.5, $T_A = 25^{\circ}C$
	ldle (Standby)	Icc2		50	100	μA	$V_{I(TxD)} \leq V_{IL}, EI = 0$
	Active	I <sub>CC3</sub>		300		μA	$V_{I(TxD)} \ge V_{IL}$ , EI = 10 mW/cm <sup>2</sup>

Notes:

3. An in-band optical signal is a pulse/sequence where the peak wavelength,  $\lambda_P$ , is defined as 850 nm  $\leq \lambda_P \leq$  900 nm, and the pulse characteristics are compliant with the IrDA Serial Infrared Physical Layer Link Specification version 1.4.

4. For in-band signals 9.6 kbit/s to 115.2 kbit/s where 9  $\mu$ W/cm<sup>2</sup>  $\leq$  El  $\leq$  500 mW/cm<sup>2</sup>.

5. Latency is defined as the time from the last TxD\_IrDA light output pulse until the receiver has recovered full sensitivity.

6. Receiver Wake Up Time is measured from V<sub>CC</sub> power ON to valid RxD\_IrDA output.

7. Transmitter Wake Up Time is measured from V<sub>CC</sub> power ON to valid light output in response to a TxD\_IrDA pulse.

8. The Optical PW is defined as the maximum time which the IrDA/RC LED will turn on, this is to prevent the long Turn On time for the IrDA and RC LED.

9. This Limits is Production Test Limits.

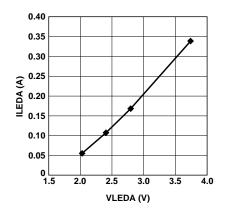


Figure 3. Typical 875 nm LED VLEDA vs. ILEDA at room temperature.

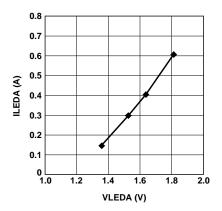


Figure 5. Typical 940 nm LED VLEDA vs. ILEDA at room temperature performance.

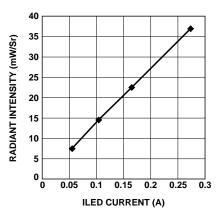


Figure 4. Typical 875 nm LED radiant intensity vs. ILED current at room temperature.

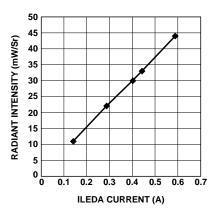


Figure 6. Typical 940 nm LED radiant intensity vs. ILED current at room temperature.

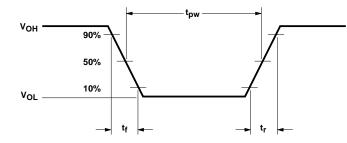


Figure 7. RXD output waveform.

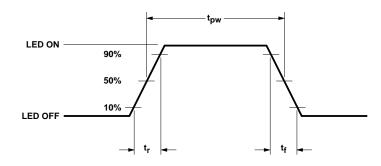


Figure 8. LED optical waveform.

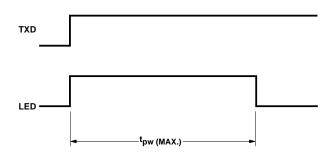
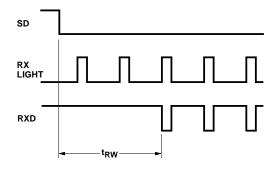
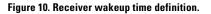


Figure 9. TXD "Stuck ON" protection.





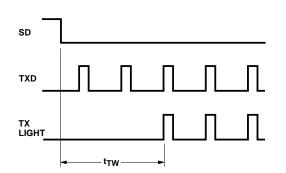


Figure 11. Transmitter wakeup time definition.

## HSDL-3003 Package Outline (With Integrated EMI Shield)

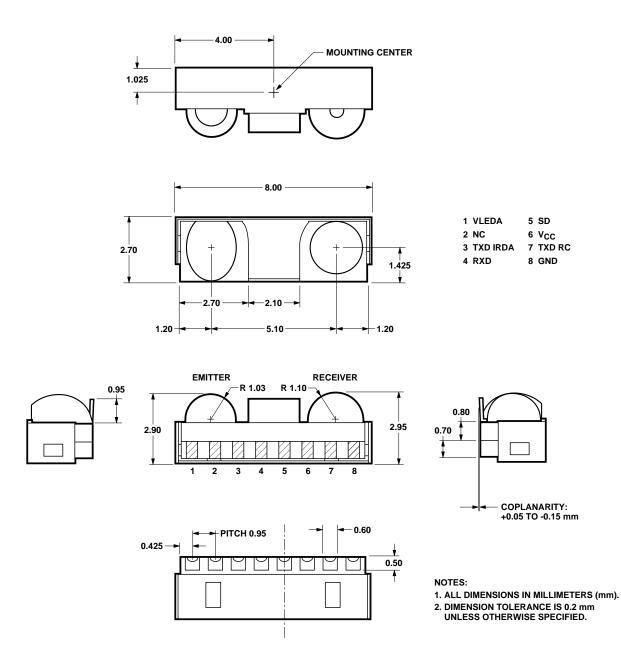


Figure 12. Package outline drawing.

#### **HSDL-3003 Tape and Reel Dimensions**

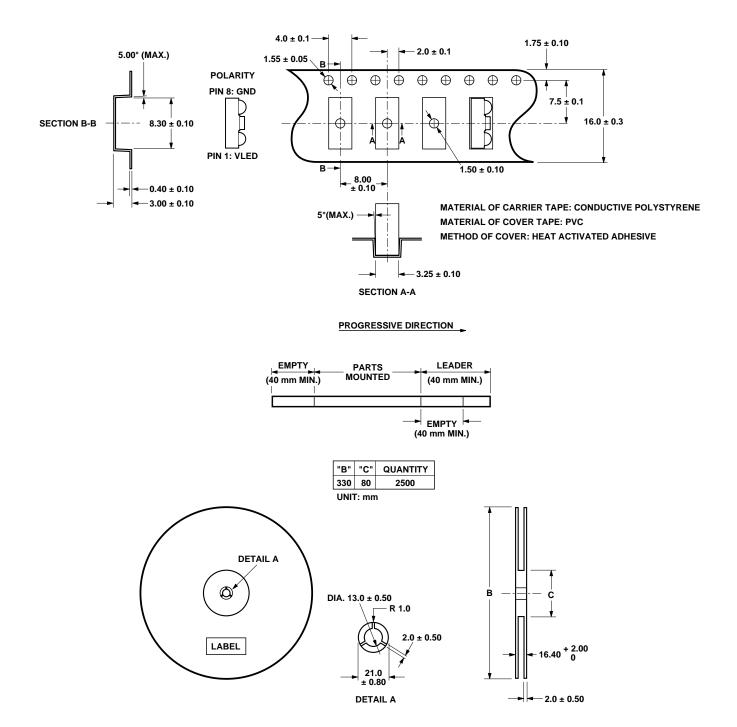


Figure 13. Tape and reel dimensions.

#### **Moisture Proof Packaging**

All HSDL-3003 options are shipped in moisture proof package. Once opened, moisture absorption begins.

This part is compliant to JEDEC Level 4.

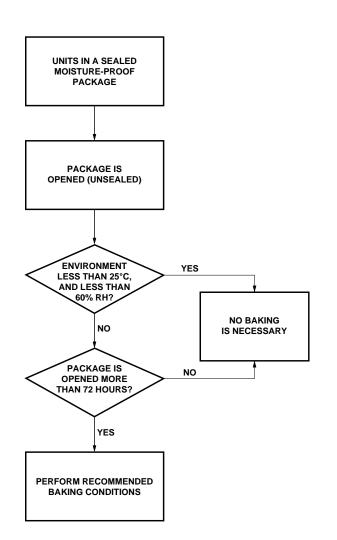


Figure 14. Baking conditions chart.

#### **Baking Conditions**

If the parts are not stored in dry conditions, they must be baked before reflow to prevent damage to the parts.

60°C	$\geq$ 48 hours
100°C	$\geq$ 4 hours
125°C	≥2 hours
150°C	$\geq$ 1 hour
	100°C 125°C

Baking should only be done once.

Storage Temperature	10°C to 30°C
Relative Humidity	below 60% RH

#### **Time from Unsealing to Soldering**

After removal from the bag, the parts should be soldered within two days if stored at the recommended storage conditions. If times longer than 72 hours are needed, the parts must be stored in a dry box.

#### **Recommended Reflow Profile**

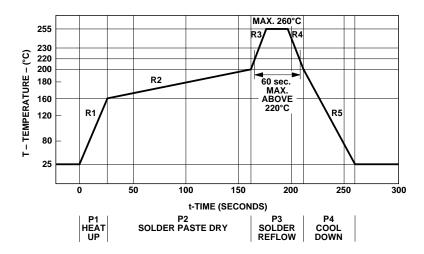


Figure 15. Reflow graph.

Process	Symbol	$\Delta T$	Maximum $\Delta T / \Delta time$
Heat Up	P1, R1	25°C to 160°C	4°C/s
Solder Paste Dry	P2, R2	160°C to 200°C	0.5°C/s
Solder Reflow	P3, R3	200°C to 255°C (260°C at 10 seconds max.)	4°C/s
	P3, R4	255°C to 200°C	−6°C/s
Cool Down	P4, R5	200°C to 25°C	–6°C/s

The reflow profile is a straightline representation of a nominal temperature profile for a convective reflow solder process. The temperature profile is divided into four process zones, each with different  $\Delta T/\Delta time$  temperature change rates. The  $\Delta T/\Delta time$ rates detailed in the above table. The temperatures are measured at the component to printed circuit board connections.

In **process zone P1**, the PC board and I/O pins are heated to a temperature of 160°C to activate the flux in the solder paste. The temperature ramp up rate, R1, is limited to 4°C per second to allow for even heating of both the PC board and HSDL-3003 I/O pins. **Process zone P2** should be of sufficient time duration (60 to –120 seconds) to dry the solder paste. The temperature is raised to a level just below the liquidus point of the solder, usually 200°C (392°F).

**Process zone P3** is the solder reflow zone. In zone P3, the temperature is quickly raised above the liquidus point of solder to  $255^{\circ}$ C (491°F) for optimum results. The dwell time above the liquidus point of solder should be between 20 and 60 seconds. It usually takes about 20 seconds to assure proper coalescence of the solder balls into liquid solder and the formation of good solder connections. Beyond a dwell time of 60 seconds, the intermetallic growth within the solder connections becomes excessive, resulting in the formation of weak and unreliable connections. The temperature is then rapidly reduced to a point below the solidus temperature of the solder, usually 200°C (392°F), to allow the solder within the connections to freeze solid.

**Process zone P4** is the cool down after solder freeze. The cool down rate, R5, from the liquidus point of the solder to 25°C (77°F) should not exceed –6°C per second maximum. This limitation is necessary to allow the PC board and transceiver's castellation I/O pins to change dimensions evenly, putting minimal stresses on the HSDL-3003.

#### **Appendix A: SMT Assembly Application Note**

#### 1.0 Solder Pad, Mask and Metal Stencil

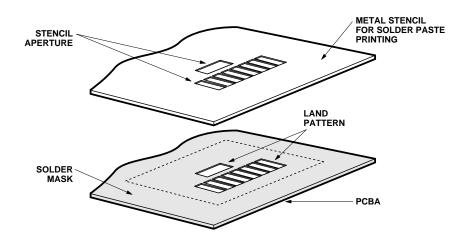


Figure 16. Stencil and PCBA.

#### **1.1 Recommended Land Pattern**

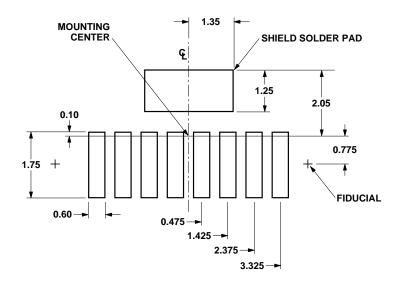


Figure 17. Land pattern.

#### 1.2 Recommended Metal Solder Stencil Aperture

It is recommended that only a 0.152 mm (0.006 inch) or a 0.127 mm (0.005 inch) thick stencil be used for solder paste printing. This is to ensure adequate printed solder paste volume and no shorting. See the table below the drawing for combinations of metal stencil aperture and metal stencil thickness that should be used.

Aperture opening for shield pad is 3.05 mm x 1.1 mm as per land pattern.

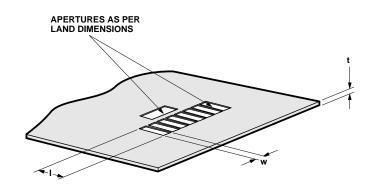


Figure 18. Solder stencil aperture.

	Aperture size(mm)		
Stencil thickness, t (mm)	length, l	width, w	
0.152 mm	$2.60\pm0.05$	$0.55\pm0.05$	
0.127 mm	$3.00\pm0.05$	$0.55\pm0.05$	

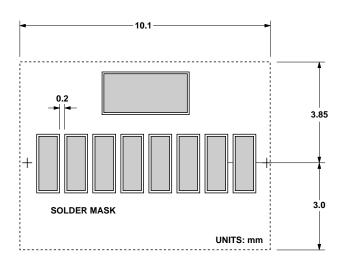
# 1.3 Adjacent Land Keepout and Solder Mask Areas

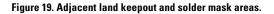
Adjacent land keepout is the **maximum space** occupied by the unit relative to the land pattern. There should be no other SMD components within this area.

The minimum solder resist strip width required to avoid solder bridging adjacent pads is **0.2 mm**.

It is recommended that two fiducial crosses be placed at midlength of the pads for unit alignment.

**Note:** Wet/Liquid Photo-Imageable solder resist/mask is recommended.





#### **Appendix B: PCB Layout Suggestion**

The following PCB layout guidelines should be followed to obtain a good PSRR and EM immunity resulting in good electrical performance. Things to note:

- 1. The ground plane should be continuous under the part, but should not extend under the shield trace.
- 2. The shield trace is a wide, low inductance trace back to the system ground. CX1, CX2 and CX3 are optional supply filter

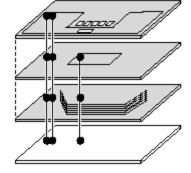
capacitors; they may be left out if a clean power supply is used.

3. VLED can be connected to either unfiltered or unregulated power supply. If VLED and Vcc share the same power supply, CX3 need not be used and the connections for CX1 and CX2 should be before the current limiting resistor R1. In a noisy environment, including capacitor CX2 can enhance supply rejection. CX1 is generally a ceramic capacitor of low inductance providing a wide frequency response while CX2 and CX3 are tantalum capacitors of big volume and fast frequency response. The use of a tantalum capacitor is more critical on the VLED line, which carries a high current.

4. Preferably a multi-layered board should be used to provide sufficient ground plane. Use the layer underneath and near the transceiver module as Vcc, and sandwich that layer between ground connected board layers. Refer to the diagram below for an example of a four-layer board.



TOP LAYER CONNECT THE METAL SHIELD AND MODULE GROUND PIN TO BOTTOM GROUND LAYER.

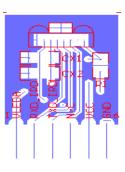


LAYER 2 CRITICAL GROUND PLANE ZONE. DO NOT CONNECT DIRECTLY TO THE MODULE GROUND PIN.

LAYER 3 KEEP DATA BUS AWAY FROM CRITICAL GROUND PLANE ZONE.

BOTTOM LAYER (GND)

The area underneath the module at the second layer, and 3 cm in all directions around the module, is defined as the critical ground plane zone. The ground plane should be maximized in this zone. Refer to application note AN1114 or the Agilent IrDA Data Link Design Guide for details. The layout below is based on a two-layer PCB.



Top View



**Bottom View** 

#### Appendix C: General Application Guide for the HSDL-3003 Infrared IrDA® Compliant 115.2 Kb/s Transceiver

#### Description

The HSDL-3003, a wide-voltage operating range infrared transceiver is a low-cost and small form factor device that is designed to address the mobile computing market such as PDAs, as well as small embedded mobile products such as digital cameras and cellular phones. It is spectrally suited to universal remote control transmission function at 940 nm typically. It is fully compliant to IrDA 1.4 low power specification from 9.6 kb/s to 115.2 kb/s, and supports most remote control codes. The design of the HSDL-3003 also includes the following unique features:

- Spectrally suited to universal remote control transmission function at 940 nm typically.
- Low passive component count.
- Shutdown mode for low power consumption requirement.

#### **Selection of Resistor R1**

Resistor R1 should be selected to provide the appropriate peak pulse LED current over different ranges of Vcc as shown on page 3 under "Recommended Application Circuit Components".

#### Interface to Recommended I/O Chips

The HSDL-3003's TXD data input is buffered to allow for CMOS drive levels. No peaking circuit or capacitor is required. Data rate from 9.6 kb/s up to 115.2 kb/s is available at the RXD pin. The TXD\_RC, (pin 7), or the TXD\_IrDA, (pin 3), can be used to send remote control codes.

The block diagrams below show how the IrDA port fits into a mobile phone and PDA platform.

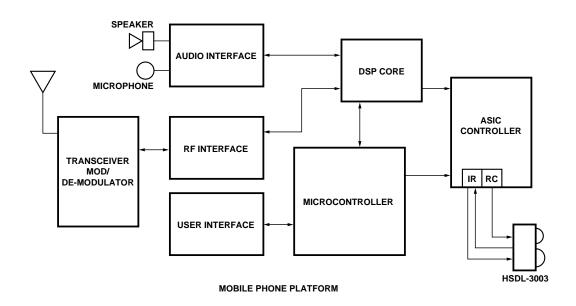


Figure 1. IR layout in mobile phone platform.

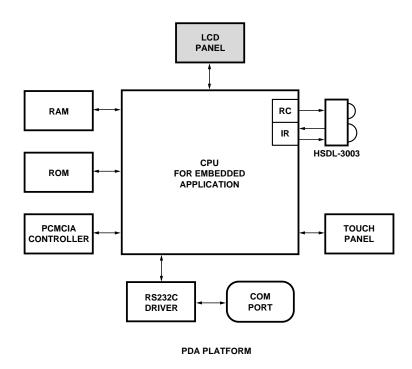


Figure 2. IR layout in PDA platform.

The link distance testing was done using typical HSDL-3003 units with SMC's FDC37C669 and FDC37N769 Super I/O controllers. An IrDA link distance of up to 70 cm was demonstrated.

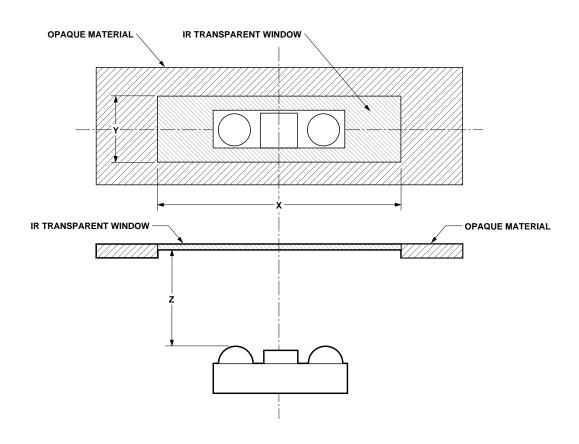
#### **Remote Control Operation**

The HSDL-3003 is spectrally suited to universal remote control transmission function at 940 nm typically. Remote control applications are not governed by any standards, owing to which there are numerous remote control codes in the market. Each of these standards results in receiver modules with different sensitivities, depending on the carrier frequencies and responsivity to the incident light wavelength.

Based on a survey of some commonly used remote control receiver modules, the irradiance is found to be in the range of  $0.05 \sim 0.07$  mW/cm2. Based on a typical irradiance of 0.05 mW/ cm2 and 0.075 mW/cm2 and turning on the RC LED, a typical link distance of 8 m and 7 m is achieved typically.

#### Appendix D: Window Designs for HSDL-3003

To ensure IrDA compliance, some constraints on the height and width of the window exist. The minimum dimensions ensure that the IrDA cone angles are met without vignetting. The maximum dimensions minimize the effects of stray light. The minimum size corresponds to a cone angle of  $30^{\circ}$  and the maximum size corresponds to a cone angle of  $60^{\circ}$ .

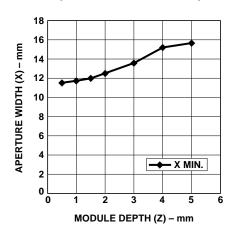


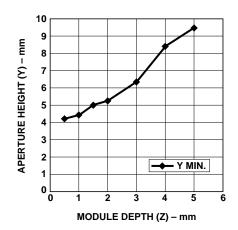
In the figure above, X is the width of the window, Y is the height of the window, and Z is the distance from the HSDL-3003 to the back of the window. Our simulations result in the following tables and graphs.

Module Depth (Z, mm)	Min Aperture Width (X, mm)	Min Aperture Height (Y, mm)
0.5	11.45	4.20
1.0	11.75	4.45
1.5	12.00	5.00
2.0	12.50	5.25
3.0	13.50	6.30
4.0	15.15	8.40
5.0	15.65	9.45

Aperture width (X) vs. module depth.

Aperture height (Y) vs. module depth.





For module depth values that are not shown on the table above, the minimum X and Y values can be interpolated. An example of this interpolation for module depth of 0.8 mm is as follows:

$$X_{\min} = \frac{0.8 - 0.5}{1.0 - 0.5} \times (11.75 - 11.45) + 11.45 = 11.63$$

$$Y_{\min} = \frac{0.8 - 0.5}{1.0 - 0.5} \times (4.45 - 4.20) + 4.20 = 4.35$$

#### **Window Material**

Almost any plastic material will work as a window material. Polycarbonate is recommended. The surface finish of the plastic should be smooth, without any texture. An IR filter dye may be used in the window to make it look black to the eye, but the total optical loss of the window should be 10% or less for best optical performance. Light loss should be measured at 875 nm. The recommended plastic materials for use as a cosmetic window are available from General Electric Plastics.

**Recommended Plastic Materials:** 

Material #	Light Transmission	Haze	<b>Refractive Index</b>
Lexan 141	88%	1%	1.586
Lexan 920A	85%	1%	1.586
Lexan 940A	85%	1%	1.586

Note: 920A and 940A are more flame retardant than 141.

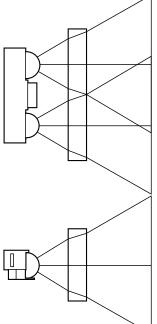
Recommended Dye: Violet #21051 (IR transmissant above 625 nm)

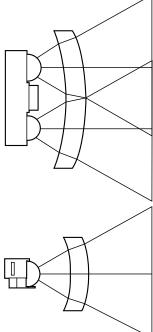
#### Shape of the Window

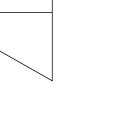
From an optics standpoint, the window should be flat. This ensures that the window will not alter either the radiation pattern of the LED, or the receive pattern of the photodiode.

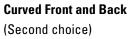
If the window must be curved for mechanical or industrial design reasons, place the same curve on the back side of the window that has an identical radius as the front side. While this will not completely eliminate the lens effect of the front curved surface, it will significantly reduce the effects. The amount of change in the radiation pattern is dependent upon the material chosen for the window, the radius of the front and back curves, and the distance from the back surface to the transceiver. Once these items are known, a lens design can be made which will eliminate the effect of the front surface curve.

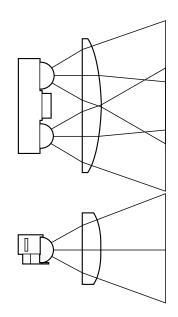
The following drawings show the effects of a curved window on the radiation pattern. In all cases, the center thickness of the window is 1.5 mm, the window is made of polycarbonate plastic, and the distance from the transceiver to the back surface of the window is 3 mm.











Curved Front, Flat Back (Do not use)

**Flat Window** 

(First choice)

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